ON Semiconductor

Is Now

Onsemí

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

Dual RF Schottky Diode

These diodes are designed for analog and digital applications, including DC based signal detection and mixing applications.

Features

- Low Capacitance (<1 pF)
- Low V_F (390 mV typical @ 1 mA)
- Low V_{FA} (1 mV typical @ 1 mA)
- Pb–Free Package is Available

Benefits

- Reduced Parasitic Losses
- Accurate Signal Measurement

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Reverse Voltage	V _R	15	V
Forward Current	١ _F	30	mA
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C
ESD Rating: Class 1 per Human Body Model Class A per Machine Model			

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	500	°C/W

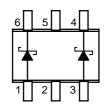
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com

RF SCHOTTKY BARRIER DIODES 15 VOLTS, 30 mA





MARKING DIAGRAM



= Specific Device Code

= Date Code

R5

Μ

= Pb–Free Package

(Note: Microdot may be in either location)

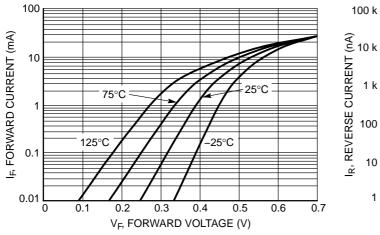
ORDERING INFORMATION

Device	Package	Shipping [†]
NSR15DW1T1	SC-88	3000/Tape & Reel
NSR15DW1T1G	SC-88 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Breakdown Voltage (I _R = 10 μA)	V _{BR}	15	20	-	V
Reverse Leakage (V _R = 1 V)	I _R	-	2	50	nA
Forward Voltage (I _F = 1 mA)	V _{F1}	-	390	415	mV
Forward Voltage (I _F = 10 mA)	V _{F2}	-	530	680	mV
Delta V _F (I _F = 1 mA, All Diodes)	ΔV_{F}	-	1	15	mV
Capacitance ($V_F = 0 V$, f = 1 MHz)	CT	-	0.8	1	pF





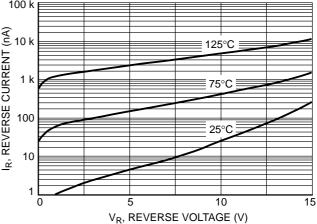


Figure 2. Reverse Current versus Reverse Voltage

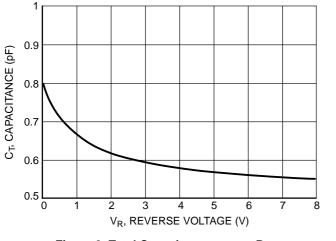
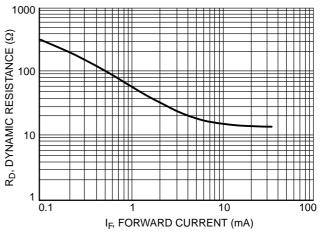


Figure 3. Total Capacitance versus Reverse Voltage





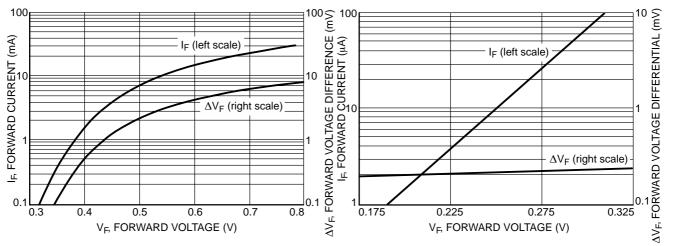
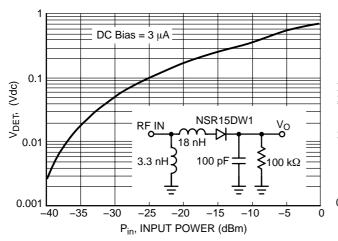


Figure 5. Typical V_F Match at Mixer Bias Levels

Figure 6. Typical V_F Match at Detector Bias Levels



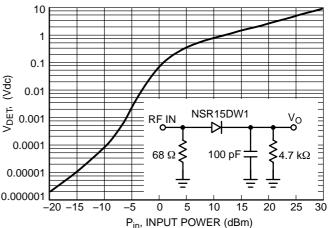


Figure 7. Typical Output Voltage versus Input Power, Small Signal Detector Operating at 850 MHz

Figure 8. Typical Output Voltage versus Input Power, Large Signal Detector Operating at 915 MHz

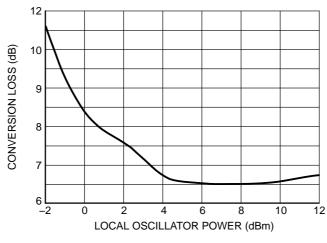
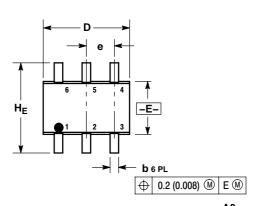


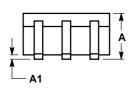
Figure 9. Typical Conversion Loss versus L.O. Drive, 2.0 GHz

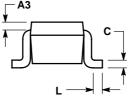
PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02 **ISSUE W**







NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2.

CONTROLLING DIMENSION: INCH. 419B-01 OBSOLETE, NEW STANDARD 419B-02. 3.

	MIL	MILLIMETERS INCHES			6	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
Е	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086

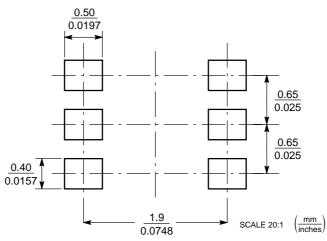
STYLE 21:

PIN 1. ANODE 1 2. N/C

3. ANODE 2 4. CATHODE 2

5. N/C 6. CATHODE 1

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications and actual performance may any content applications. intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, ad distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, and claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative